SY8036
High Efficiency 5.5V, 6A, 1 MHz Synchronous Step Down Regulator

General Description

SY8036 is a high-efficiency 1 MHz synchronous step-down DC-DC regulator IC capable of delivering up to 6A output current. SY8036 operates over a wide input voltage range from 2.7V to 5.5V and integrates the main switch and the synchronous switch with very low $R_{DS(ON)}$ to minimize the conduction losses.

Low output voltage ripple and small external inductor and capacitor sizes are achieved with 1MHz switching frequency.

Ordering Information

SY8036□(□□)□

- Temperature Code
- Package Code
- Optional Spec Code

Ordering Number	Package Type	Note
SY8036DBC	DFN3×3-10	6A

Features

- Low $R_{DS(ON)}$ for internal switches (top/bottom): 40/30mΩ
- Input voltage range: 2.7-5.5V
- 1 MHz switching frequency minimizes the external components
- External adjustable softstart limits the inrush current
- 100% dropout operation
- Power good indicator
- RoHS Compliant and Halogen Free
- Compact package: DFN3x3-10

Applications

- LCD TV
- Access Point Router
- Notebook PC
- Server

Typical Applications

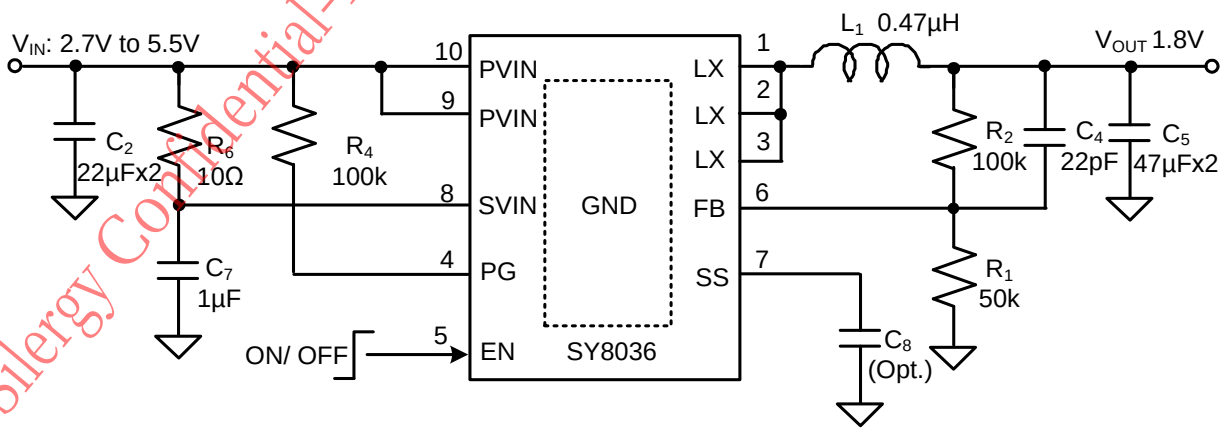
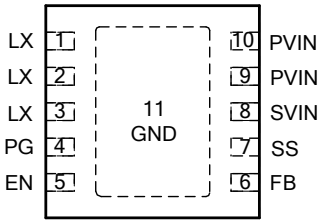


Figure 1: Typical application circuit diagram (V_{OUT}=1.8V)

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Pinout (top view)



Top Mark: CS*xyz* (device code: CS, ***x=year code, y=week code, z= lot number code)***

Pin Name	Pin Number	Pin Description
EN	5	Enable control. Pull high to turn on. Integrated 1M pull-down resistor.
GND	11	Ground pin.
LX	1,2,3	Phase node pin. Connect this pin to the inductor.
SVIN	8	Signal power input pin. Decouple this pin to GND pin with at least 1μF ceramic cap.
PVIN	9,10	Power input pin. Decouple this pin to GND pin with at least 22μF ceramic cap.
FB	6	Output feedback pin. Connect this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: $V_{OUT}=0.6\times(1+R_1/R_2)$.
PG	4	Power good indicator(Open drain output). Low if the output < 90% of regulation voltage; High otherwise. Connect a pull-up resistor to the input.
SS	7	Softstart programming pin. Connect a capacitor from this pin to ground to program the softstart time. Tss=Max(600us, Css×0.6V/10uA).

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Absolute Maximum Ratings (Note 1)

Supply Input Voltage ---------- 0.3V to 6.5V
Enable, FB Voltage---------- 0.3V to V_{IN} + 0.6V
Power Dissipation, P_D @ T_A = 25℃ DFN3X3-10 ---------- 2.6W
Package Thermal Resistance (Note 2)
θ_{JA} ---------- 38℃/W
θ_{JC} ---------- 8℃/W
Junction Temperature Range ---------- -40℃ to 150℃
Lead Temperature (Soldering, 10 sec.) ---------- 260℃
Storage Temperature Range ---------- -65℃ to 150℃
ESD Susceptibility (Note 2)
HBM (Human Body Mode) ---------- 2kV
MM (Machine Mode) ---------- 200V
Dynamic LX voltage in 50ns duration ---------- IN+3V to GND-4V

Recommended Operating Conditions (Note 3)

Supply Input Voltage ---------- 2.7V to 5.5V
Junction Temperature Range ---------- -40℃ to 125℃
Ambient Temperature Range ---------- -40℃ to 85℃

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Electrical Characteristics

(V_{IN} = 5V, V_{OUT} = 2.5V, L = 0.47μH, C_{OUT} = 47μFx2, T_A = 25℃, I_{OUT} = 1A unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{IN}		2.7		5.5	V
Shutdown Current	I_{SHDN}	EN=0		0.1	1	μA
Quiescent Current	I_Q	I_{OUT}=0, V_{FB}=V_{REF} · 105%		150		μA
Feedback Reference Voltage	V_{REF}		0.591	0.6	0.609	V
FB Input Current	I_{FB}	V_{FB}=V_{IN}	-50		50	nA
PFET R_{ON}	$R_{DS(ON)-P}$			40		mΩ
NFET R_{ON}	$R_{DS(ON)-N}$			30		mΩ
PFET Current Limit	I_{LIM}		7.5			A
EN Rising Threshold	V_{ENH}		1.5			V
EN Falling Threshold	V_{ENL}				0.4	V
Input UVLO Threshold	V_{UVLO}				2.7	V
UVLO Hysteresis	V_{HYS}			0.2		V
Oscillator Frequency	F_{OSC}	I_{OUT}=1A		1		MHz
Min ON Time				80		ns
Max Duty Cycle			100			%
Thermal Shutdown Temperature	T_{SD}	Shutdown temperature		150		℃
		Hysteresis		10		
Soft Start Time	t_{SS}	C_{SS}=100nF		6		ms
		Without C_{SS}		0.6		
Phase Node Discharge Resistance	R_{DISCHG}			40		Ω

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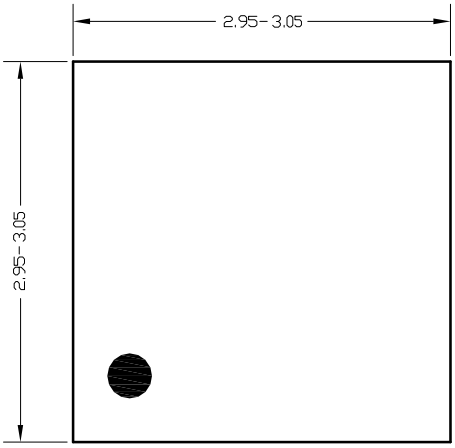
Note 1: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: Θ_{JA} is measured in the natural convection at T_A = 25 ℃ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Test condition: Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

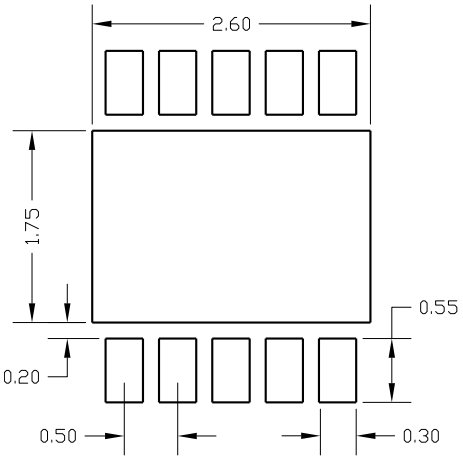
Note 3: The device is not guaranteed to function outside its operating conditions.

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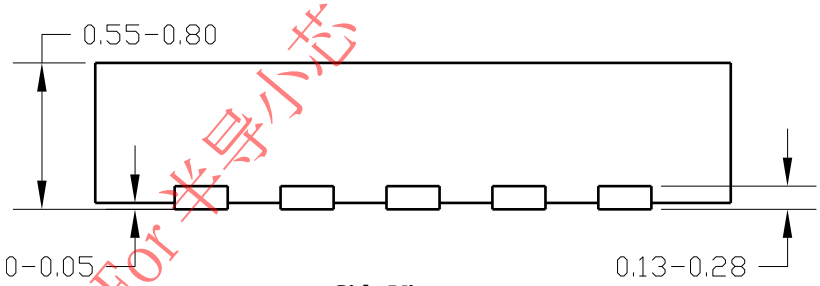
DFN3x3-10 Package outline



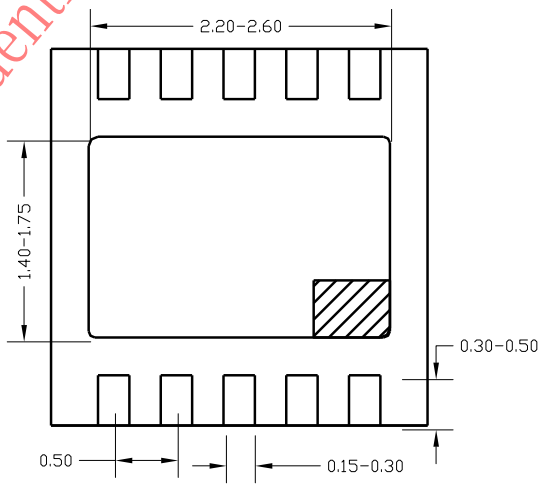
Top View

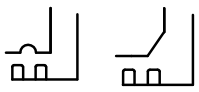


PCB layout (recommended)



Side View





Detail A
Pin1 identifier: two options

Bottom View

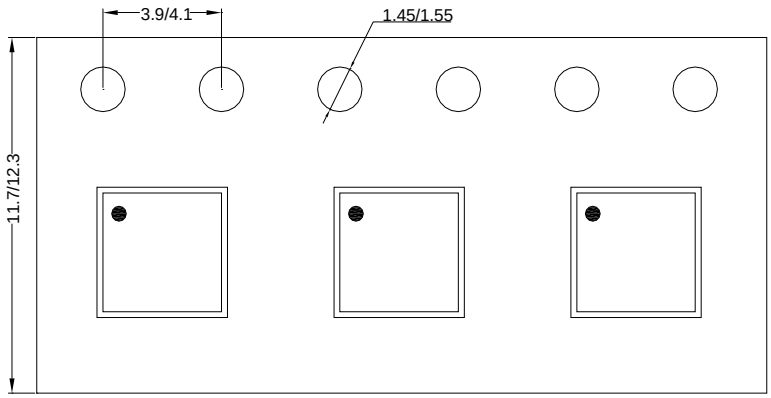
Notes: All dimensions are in millimeters and exclude mold flash & metal burr.

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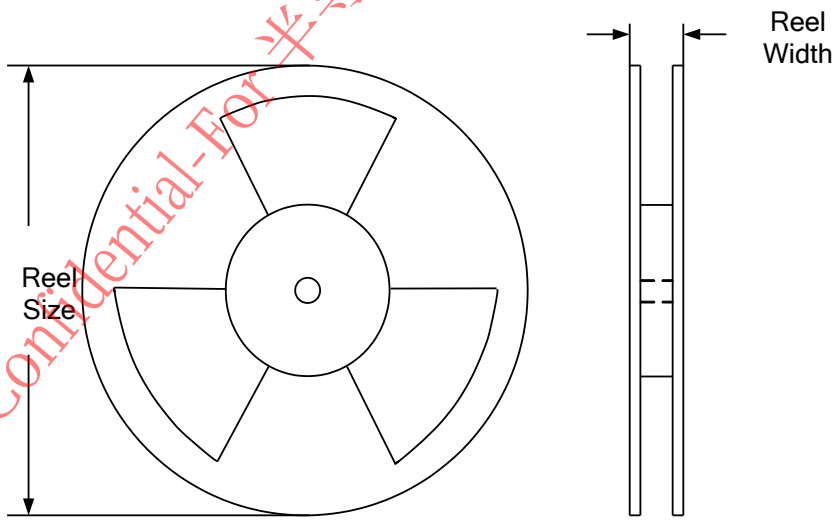
Taping & Reel Specification

1. DFN3x3-10 taping orientation



Feeding direction →

2. Carrier Tape & Reel specification for packages



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Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Reel width(mm)	Trailer length(mm)	Leader length (mm)	Qty per reel
DFN3x3	10	8	13"	12.4	400	400	5000

3. Others: NA

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